L Number	Hits	Search Text	DB	Time stamp
13	2	(("6225192") or ("6020252")).PN.	USPAT; US-PGPUB	2004/05/11 13:49
14	1464746	@ad>19970515 @rlad>19970515	USPAT; US-PGPUB	2004/05/11
15	82	"smart-cut" and keV	USPAT; US-PGPUB	2004/05/11
16	0	("smart-cut" and keV) not (@ad>19970515 @rlad>19970515)	USPAT; US-PGPUB	2004/05/11
17	206	"smart-cut"	USPAT; US-PGPUB	2004/05/11
18	0	"smart-cut" not (@ad>19970515 @rlad>19970515)	USPAT; US-PGPUB	2004/05/11
19	2075	hydrogen with (implantation or implant\$3)	USPAT; US-PGPUB	2004/05/11
20	675464	bond\$3	USPAT; US-PGPUB	2004/05/11
21	1267	(hydrogen with (implantation or implant\$3)) and bond\$3	USPAT; US-PGPUB	2004/05/11
22	2253397	split\$ or splitting or separat\$3	USPAT; US-PGPUB	2004/05/11
23	599815	cleav\$3 break\$3	USPAT; US-PGPUB	2004/05/11
24	2431879	(split\$ or splitting or separat\$3) or (cleav\$3 break\$3)	USPAT; US-PGPUB	2004/05/11 14:47
27	1073	((hydrogen with (implantation or implant\$3)) and bond\$3) and ((split\$ or splitting or	USPAT; US-PGPUB	2004/05/11 13:57
28	193	separat\$3) or (cleav\$3 break\$3)) (((hydrogen with (implantation or implant\$3)) and bond\$3) and ((split\$ or splitting or	USPAT; US-PGPUB	2004/05/11 13:58
		separat\$3) or (cleav\$3 break\$3))) not (@ad>19970515 @rlad>19970515)		
29	551738	semiconductor or ic or "integrated circuit" or microelectronic	USPAT; US-PGPUB	2004/05/11 14:46
30	419932	silicon	USPAT; US-PGPUB	2004/05/11 13:58
31	153	((((hydrogen with (implantation or implant\$3)) and bond\$3) and ((split\$ or splitting or separat\$3) or (cleav\$3 break\$3))) not (@ad>19970515 @rlad>19970515)) and silicon	USPAT; US-PGPUB	2004/05/11 13:58
33	128	(semiconductor or ic or "integrated circuit" or microelectronic) and ((((hydrogen with (implantation or implant\$3)) and bond\$3) and ((split\$ or splitting or separat\$3) or (cleav\$3 break\$3))) not (@ad>19970515 @rlad>19970515)) and silicon)	USPAT; US-PGPUB	2004/05/11 13:59
34	899	hydrogen with (implantation or implant\$3)	EPO; JPO; DERWENT; IBM_TDB	2004/05/11 14:46
35	1237339	semiconductor or ic or "integrated circuit" or microelectronic	EPO; JPO; DERWENT; IBM_TDB	2004/05/11 14:46
37	1805237	split\$ or splitting or separat\$3 or cleav\$3 or break\$3	EPO; JPO; DERWENT; IBM_TDB	2004/05/11 14:48
38	73	(hydrogen with (implantation or implant\$3)) and (semiconductor or ic or "integrated circuit" or microelectronic) and (split\$ or splitting or separat\$3 or cleav\$3 or break\$3)	EPO; JPO; DERWENT; IBM_TDB	2004/05/11 14:49
-	65379	438/\$.ccls.	USPAT; US-PGPUB	2004/03/31 19:04

-	25311	keV	USPAT;	2004/05/10
			US-PGPUB	18:08